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FORM PTO-1449

Dock t Number (Optional)
81788.0251Application Number
Not Assigned; Parent 10/281,852**INFORMATION DISCLOSURE CITATION
IN AN APPLICATION**

(Use several sheets if necessary)

Applicant

FURUKAWA, et al.

Filing Date
June 23, 2003Group Art Unit
Not Assigned**U.S. PATENT DOCUMENTS**

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
Gu	6,404,125	06-2002	Garbuzov et al.	313	499	
I	6,340,824	01-2002	Komoto et al.	257	99	
I	5,998,925	12-1999	Shimizu et al.	313	503	
Gu	5,813,752	09-1998	Singer et al.	362	293	

FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						YES	NO
	2000-082849	03/21/00	JAPAN				
	11-087778	03/30/99	JAPAN				
	10-012916	01/16/98	JAPAN				

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

	Thick GzN Epitaxial Growth with Low Dislocation Density by Hydride Vapor Phase Epitaxy – USUI, et al./ Japanese Journal of Applied Physics 36, Part 2, No. 7B, L899 (1997)

EXAMINER

G. M. [Signature]

DATE CONSIDERED

12/14/03

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.